

DATA SHEET

74F37

Quad 2-input NAND buffer

Product specification

1990 May 24

IC15 Data Handbook

Quad 2-input NAND buffer

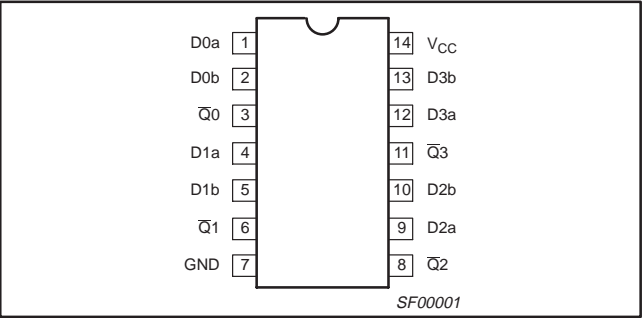
74F37

TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
74F37	3.5ns	13mA

ORDERING INFORMATION

DESCRIPTION	COMMERCIAL RANGE V _{CC} = 5V ±10%, T _{amb} = 0°C to +70°C	PKG DWG #
14-pin plastic DIP	N74F37N	SOT27-1
14-pin plastic SO	N74F37D	SOT108-1

PIN CONFIGURATION

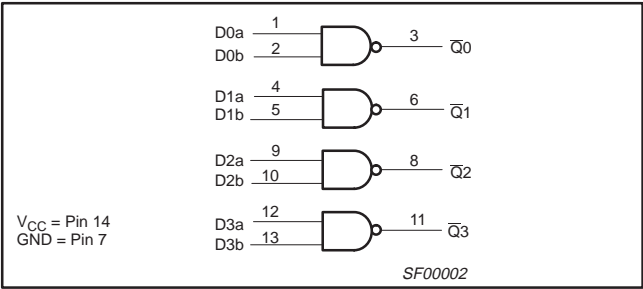


INPUT AND OUTPUT LOADING AND FAN OUT TABLE

PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
Dna, Dnb	Data inputs	1.0/2.0	20µA/1.2mA
Qn	Data outputs	750/106.6	15mA/64mA

NOTE: One (1.0) FAST unit load is defined as: 20µA in the High state and 0.6mA in the Low state.

LOGIC DIAGRAM

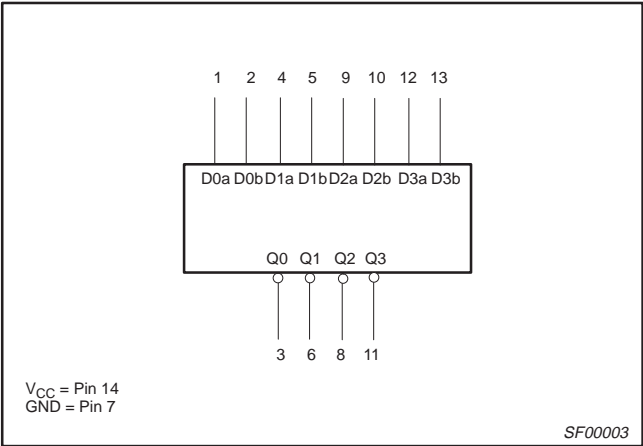


FUNCTION TABLE

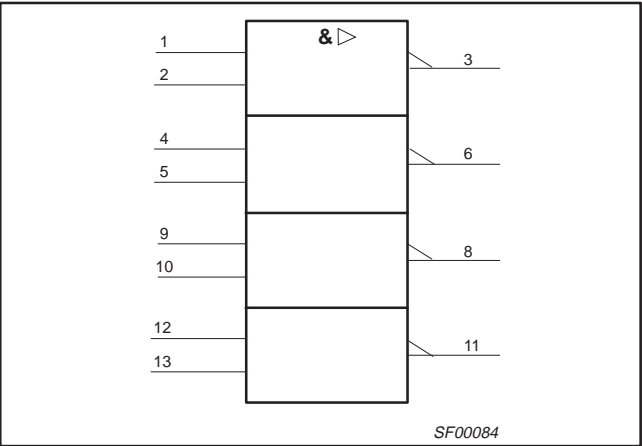
INPUTS		OUTPUT
Dna	Dnb	Qn
L	L	H
L	H	H
H	L	H
H	H	L

- NOTES:
- 1. H = High voltage level
 - 2. L = Low voltage level

LOGIC SYMBOL



IEC/IEEE SYMBOL



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74F37

ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limits set forth in this table may impair the useful life of the device.
Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER	RATING	UNIT
V_{CC}	Supply voltage	−0.5 to +7.0	V
V_{IN}	Input voltage	−0.5 to +7.0	V
I_{IN}	Input current	−30 to +5	mA
V_{OUT}	Voltage applied to output in High output state	−0.5 to V_{CC}	V
I_{OUT}	Current applied to output in Low output state	128	mA
T_{amb}	Operating free-air temperature range	0 to +70	°C
T_{stg}	Storage temperature range	−65 to +150	°C

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS			UNIT
		MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5.0	5.5	V
V_{IH}	High-level input voltage	2.0			V
V_{IL}	Low-level input voltage			0.8	V
I_{IK}	Input clamp current			−18	mA
I_{OH}	High-level output current			−15	mA
I_{OL}	Low-level output current			64	mA
T_{amb}	Operating free-air temperature range	0		+70	°C

DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

SYMBOL	PARAMETER		TEST CONDITIONS ¹			LIMITS			UNIT
						MIN	TYP ²	MAX	
V _{OH}	High-level output voltage		V _{CC} = MIN, V _{IL} = MAX, V _{IH} = MIN	I _{OH} = −1mA	±10%V _{CC}	2.5			V
					±5%V _{CC}	2.7	3.4		
				I _{OH} = −15mA	±10%V _{CC}	2.0			V
					±5%V _{CC}	2.0			
V _{OL}	Low-level output voltage		V _{CC} = MIN, V _{IL} = MAX, V _{IH} = MIN	I _{OL} = MAX	±10%V _{CC}			0.55	V
					±5%V _{CC}		0.42	0.55	
V _{IK}	Input clamp voltage		V _{CC} = MIN, I _I = I _{IK}				−0.73	−1.2	V
I _I	Input current at maximum input voltage		V _{CC} = MAX, V _I = 7.0V					100	μA
I _{IH}	High-level input current		V _{CC} = MAX, V _I = 2.7V					20	μA
I _{IL}	Low-level input current		V _{CC} = MAX, V _I = 0.5V					−1.2	mA
I _{OS}	Short-circuit output current ³		V _{CC} = MAX			−100		−225	mA
I _{CC}	Supply current (total)	I _{CCH}	V _{CC} = MAX		V _{IN} = GND		3.0	6.0	mA
		I _{CCL}			V _{IN} = 4.5V		23	33	

NOTES:

- For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.
- All typical values are at $V_{CC} = 5\text{V}$, $T_{amb} = 25^\circ\text{C}$.
- Not more than one output should be shorted at a time. For testing I_{OS} , the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

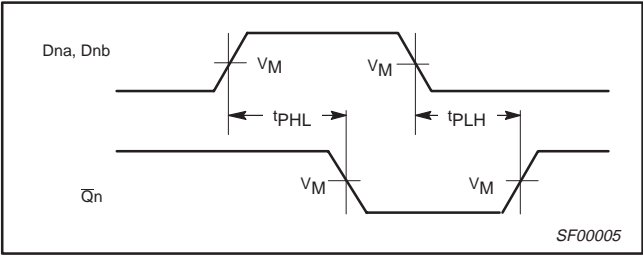
Quad 2-input NAND buffer

74F37

AC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITION	LIMITS					UNIT
			V _{CC} = +5.0V T _{amb} = +25°C C _L = 50pF, R _L = 500Ω			V _{CC} = +5.0V ± 10% T _{amb} = 0°C to +70°C C _L = 50pF, R _L = 500Ω		
			MIN	TYP	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay D _{na} , D _{nb} to Q _n	Waveform 1	2.5 1.5	3.5 2.5	5.5 4.5	2.0 1.5	6.5 5.0	ns

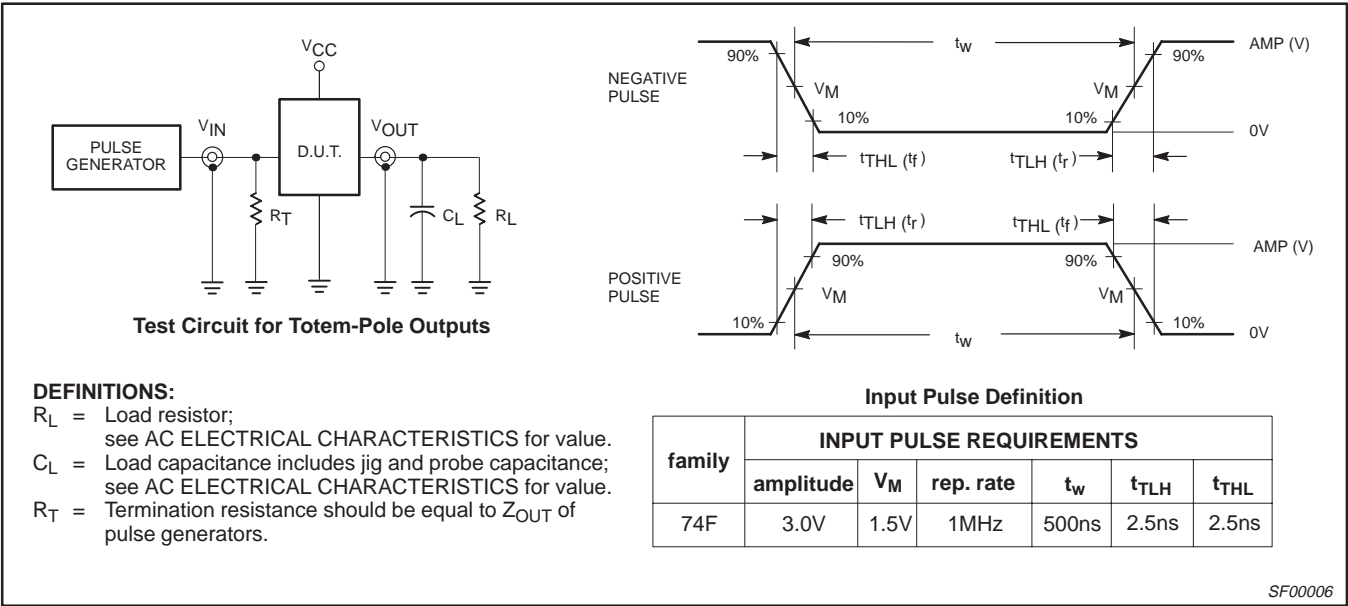
AC WAVEFORMS



Waveform 1. Propagation Delay for Inverting Outputs

NOTE:
For all waveforms, $V_M = 1.5V$.

TEST CIRCUIT AND WAVEFORMS

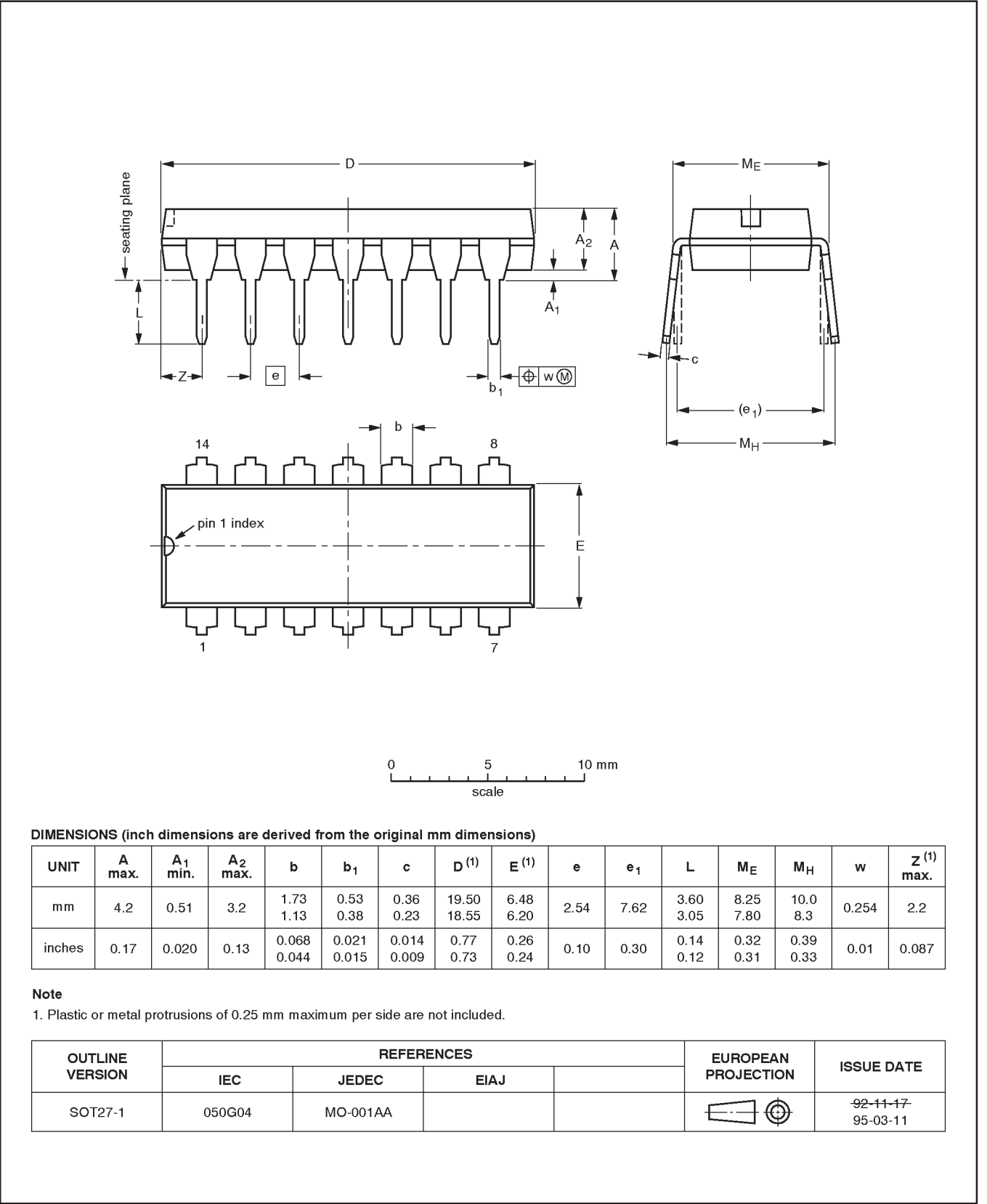


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74F37

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1

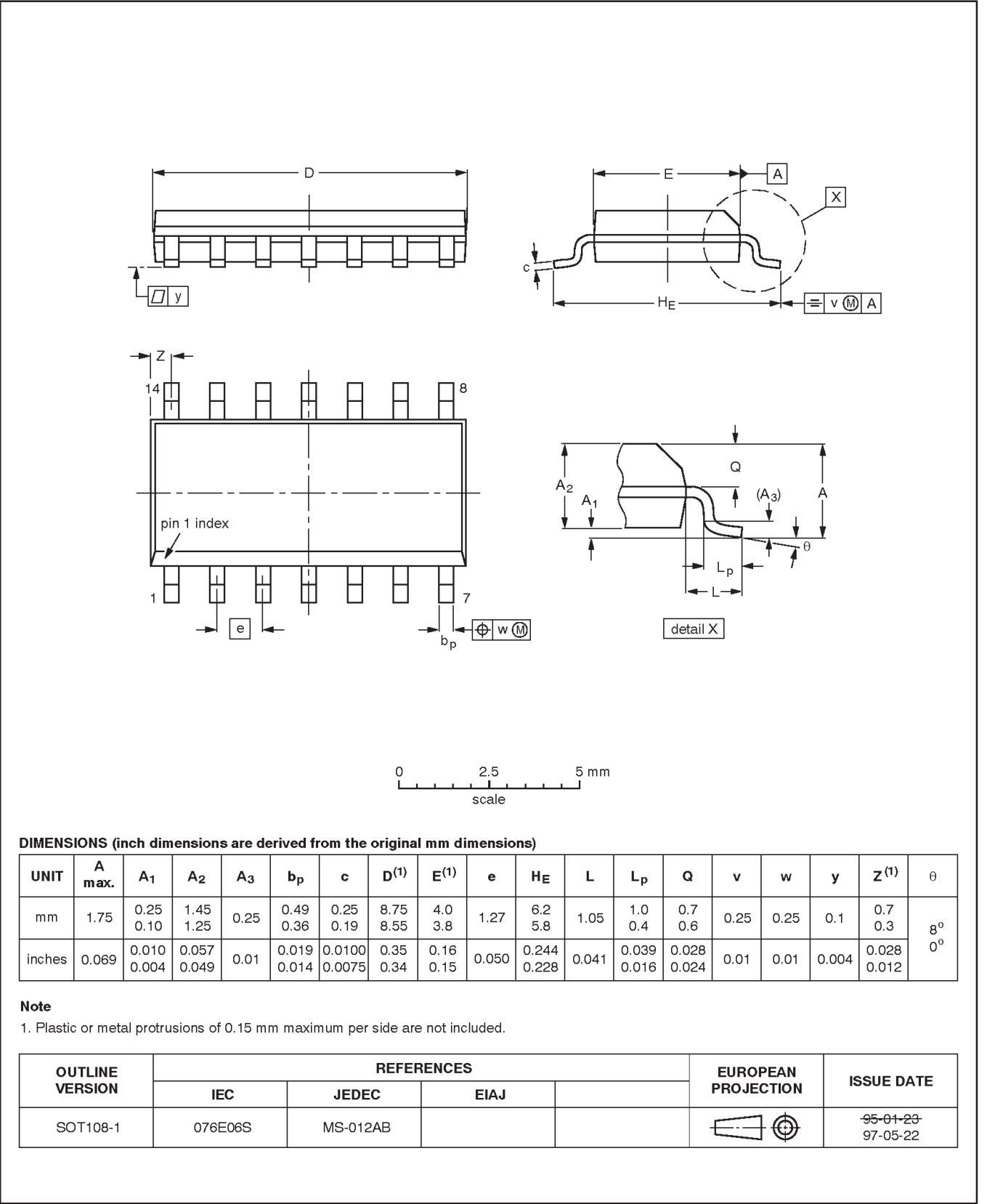


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74F37

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



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74F37

NOTES

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74F37

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

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